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Thyristor Surge Protectors

High Voltage Bidirectional

NTVB Series Thyristor Surge Protector Devices (TSPD) protect telecommunication circuits such as central office, access, and customer premises equipment from overvoltage conditions. These are bidirectional devices so they are able to have functionality of 2 devices in one package, saving valuable space on board layout.

These devices will act as a crowbar when overvoltage occurs and will divert the energy away from circuit or device that is being protected.

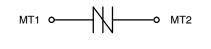
Use of the NTVB Series in equipment will help meet various regulatory requirements including: GR-1089-CORE, IEC 61000-4-5, ITU K.20/21/45, IEC 60950, TIA-968-A, FCC Part 68, EN 60950, UL 1950.



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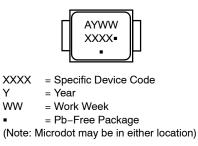
BIDIRECTIONAL SURFACE MOUNT THYRISTOR 64 – 350 VOLTS





SMB JEDEC DO-214AA CASE 403C

MARKING DIAGRAM



Υ

ORDERING INFORMATION

See detailed ordering and shipping information on page 4 of this data sheet.

ELECTRICAL PARAMETERS

| | V _{DRM} | V _(BO) | VT | I _{DRM} | I _(BO) | г | Ι _Η |
|--------------|------------------|-------------------|----|------------------|-------------------|-----|----------------|
| Device | v | v | v | μΑ | mA | Α | mA |
| NTVB058NSx-L | 58 | 77 | 4 | 5 | 800 | 2.2 | 150 |
| NTVB065NSx-L | 65 | 88 | 4 | 5 | 800 | 2.2 | 150 |
| NTVB090NSx-L | 90 | 130 | 4 | 5 | 800 | 2.2 | 150 |
| NTVB170Sx-L | 170 | 265 | 4 | 5 | 800 | 2.2 | 150 |
| NTVB170NSx-L | 170 | 220 | 4 | 5 | 800 | 2.2 | 150 |
| NTVB180Sx-L | 170 | 240 | 4 | 5 | 800 | 2.2 | 150 |
| NTVB200Sx-L | 200 | 320 | 4 | 5 | 800 | 2.2 | 150 |
| NTVB220NSx-L | 220 | 300 | 4 | 5 | 800 | 2.2 | 150 |
| NTVB270Sx-L | 270 | 365 | 4 | 5 | 800 | 2.2 | 150 |
| NTVB275NSx-L | 275 | 350 | 4 | 5 | 800 | 2.2 | 150 |
| NTVB300Sx-L | 300 | 400 | 4 | 5 | 800 | 2.2 | 150 |

SURGE DATA RATINGS

| | Wave | eform | X = S | eries ra | tings | |
|---------------|---------------|---------------|-------|----------|-------|-------|
| Specification | Voltage μs | Current μs | А | в | с | Unit |
| GR-1089-CORE | 2x10 | 2x10 | 150 | 250 | 500 | A(pk) |
| TIA-968-A | 10x160 | 10x160 | 90 | 150 | 200 | |
| GR-1089-CORE | 10x360 | 10x360 | 75 | 125 | 175 | |
| TIA-968-A | 10x560 | 10x560 | 50 | 100 | 150 | |
| ITU-T K.20/21 | 10x700 | 5x310 | 75 | 100 | 200 | |
| GR-1089-CORE | 10x1000 | 10x1000 | 50 | 80 | 100 | |

*91 Recognized Components

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ELECTRICAL CHARACTERISTICS (T_A = 25° C unless otherwise noted)

| Characteristics (Notes 1, 2, 3) | | Min | Тур | Max | Unit |
|--|--|---|-----|---|----------|
| Breakover Voltage (Both Polarities) NTVB058NSx-L NTVB065NSx-L NTVB170Sx-L NTVB170NSx-L NTVB170NSx-L NTVB180Sx-L NTVB200Sx-L NTVB220NSx-L NTVB270Sx-L NTVB275NSx-L NTVB300Sx-L | V _(BO) | | | 77 88 130 265 220 240 320 300 365 350 400 | V |
| Off-State Voltage (Both Polarities) NTVB058NSx-L NTVB065NSx-L NTVB170Sx-L NTVB170NSx-L NTVB170NSx-L NTVB180Sx-L NTVB200Sx-L NTVB220NSx-L NTVB270Sx-L NTVB275NSx-L NTVB300Sx-L | V _{DRM} | 58 65 90 170 170 200 220 270 275 300 | | | V |
| $ \begin{array}{ll} \mbox{Off State Current} & (V_{D1} = 50 \ V \) \ \mbox{Both Polarities} \\ (V_{D2} = V_{DRM} \) \ \mbox{Both Polarities} \end{array} $ | I _{DRM1} I _{DRM2} | | | 2.0 5.0 | μΑ μΑ |
| Holding Current (Both Polarities) (Note 3) V_S = 500 V; I _T = 2.2 A | Ι _Η | 150 | 250 | - | mA |
| On–State Voltage I _T = 1.0 A(pk) (PW = 300 μ Sec, DC = 2%) | V _T | - | - | 4.0 | V |
| Maximum Non-Repetitive Rate of Change of On-State Current (Note 1) (Haefely test method, 1.0 pk < 100 A) | | - | - | 500 | A/μSec |
| Critical Rate of Rise of Off–State Voltage (Linear Waveform, V_D = 0.8 V_{DRM} , T_J = 25°C) | dv/dt | 5.0 | - | - | kV/μSec |

CAPACITANCE

| | | | Тур | | |
|---|--------|--|---|---|------|
| Characteristics | Symbol | Α | В | С | Unit |
| (f=1.0 MHz, 1.0 V _{rms} , 2 Vdc bias) NTVB058NSx-L NTVB065NSx-L NTVB090NSx-L NTVB170Sx-L NTVB170NSx-L NTVB180Sx-L NTVB200Sx-L NTVB220NSx-L | Co | 84 79 58 39 39 37 36 33 | 129 123 95 150 59 59 56 52 | 222 198 154 195 99 97 110 81 | pF |
| NTVB270Sx–L NTVB275NSx–L NTVB300Sx–L | | 31 28 28 | 47 44 44 | 76 97 71 | |

Electrical parameters are based on pulsed test methods.
Measured under pulsed conditions to reduce heating
Allow cooling before testing second polarity.

SURGE RATINGS

| Characteristics | Symbol | Α | В | С | Unit |
|--|--|-----------------------------------|---------------------------------------|--|-------|
| Nominal Pulse Surge Short Circuit Current Non – Repetitive Double Exponential Decay Waveform (Notes 4, 5 and 6) 2 x 10 μSec 10 x 160 μSec 10 x 360 μSec 10 x 560 μSec 10 x 700 μSec 10 x 1000 μSec | Ipps1 Ipps3 Ipps4 Ipps5 Ipps6 Ipps7 | 150 90 75 50 75 50 | 250 150 125 100 100 80 | 500 200 150 150 200 100 | A(pk) |

4. Allow cooling before testing second polarity.

Measured under pulse conditions to reduce heating.
Nominal values may not represent the maximum capability of a device.

THERMAL CHARACTERISTICS

| Symbol | Rating | Value | Unit |
|------------------|--|-------------|------|
| T _{STG} | Storage Temperature Range | –65 to +150 | °C |
| TJ | Operating Temperature Range | -40 to +150 | °C |
| R _{0JA} | Thermal Resistance: Junction-to-Ambient Per EIA/JESD51-3, PCB = FR4 3"x4.5"x0.06" Fan out in a 3x3 inch pattern, 2 oz copper track. | 90 | °C/W |

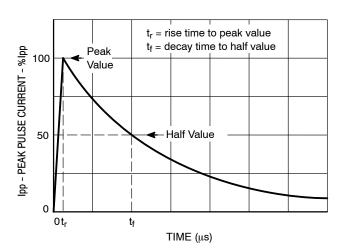


Figure 1. Exponential Decay Pulse Waveform

| Symbol | Parameter |
|-------------------|------------------------|
| V _{DRM} | Peak Off State Voltage |
| V _(BO) | Breakover Voltage |
| I _(BO) | Breakover Current |
| Ι _Η | Holding Current |
| V _T | On State Voltage |
| I _T | On State Current |

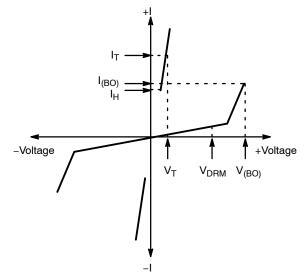


Figure 2. Voltage Current Characteristics of TSPD

ORDERING INFORMATION

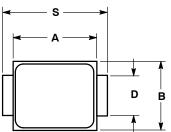
| Part Number | Marking | Case | Shipping [†] |
|--------------|---------|------------|-----------------------|
| NTVB058NSB-L | 58NB | | |
| NTVB058NSC-L | 58NC | | |
| NTVB065NSA-L | 65NA | | |
| NTVB065NSC-L | 65NC | | |
| NTVB090NSA-L | 90NA | | |
| NTVB170SA-L | 170A | 7 | |
| NTVB170SC-L | 170C | | |
| NTVB170NSC-L | 17NC | | |
| NTVB180SA-L | 180A | | |
| NTVB200SA-L | 200A | SMB | |
| NTVB200SB-L | 200B | (Pb-Free) | 2500 / Tape and Reel |
| NTVB200SC-L | 200C | 7 | |
| NTVB220NSC-L | 22NC | 7 | |
| NTVB270SA-L | 270A | 7 | |
| NTVB270SB-L | 270B | 7 | |
| NTVB270SC-L | 270C | \neg $ $ | |
| NTVB275NSC-L | 27NC | \neg $ $ | |
| NTVB300SA-L | 300A | \neg $ $ | |
| NTVB300SB-L | 300B | \neg $ $ | |
| NTVB300SC-L | 300C | \neg $ $ | |

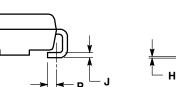
†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

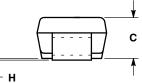
PACKAGE DIMENSIONS

CASE

SMB CASE 403C-01 ISSUE A







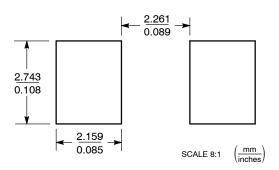
NOTES:

 DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.

2. CONTROLLING DIMENSION: INCH. 3. D DIMENSION SHALL BE MEASURED WITHIN DIMENSION P.

| | INC | HES | MILLIM | IMETERS | | |
|-----|-----------|--------|--------|---------|--|--|
| DIM | MIN | MAX | MIN | MAX | | |
| Α | 0.160 | 0.180 | 4.06 | 4.57 | | |
| В | 0.130 | 0.150 | 3.30 | 3.81 | | |
| С | 0.075 | 0.095 | 1.90 | 2.41 | | |
| D | 0.077 | 0.083 | 1.96 | 2.11 | | |
| Н | 0.0020 | 0.0060 | 0.051 | 0.152 | | |
| J | 0.006 | 0.012 | 0.15 | 0.30 | | |
| Κ | 0.030 | 0.050 | 0.76 | 1.27 | | |
| Ρ | 0.020 REF | | 0.51 | REF | | |
| S | 0.205 | 0.220 | 5.21 | 5.59 | | |

SOLDERING FOOTPRINT*



*For additional information on our Pb–Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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